



PATENT  
Atty. Ref. P97,0027

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANTS: **Hiroshi Tayanaka**  
SERIAL NO.: **08/818,239** GROUP ART UNIT: **2813**  
FILED: **March 14, 1997** EXAMINER: **K. Christianson**  
FOR: **"METHOD FOR MAKING THIN FILM SEMICONDUCTOR,  
SOLAR CELL, AND LIGHT EMITTING DIODE"**

Assistant Commissioner for Patents  
Washington, D.C. 20231

AMENDMENT

RECEIVED  
APR 13 1999  
TECHNOLOGY CENTER 2800

Dear Sir:

In response to the Office Action mailed December 3, 1998, kindly amend the above-identified application as follows:

IN THE SPECIFICATION:

At page 21, line 2, please delete "Si<sub>1-y</sub>Ge<sub>y</sub>" and insert --Si<sub>1-y</sub> and Ge<sub>y</sub>--.

At page 29, lines 6-7, please delete "around here" and insert --at this location--.

At page 33, line 3, please delete "around here" and insert --at this location--.

At page 40, line 3, please delete "mA/cm<sup>2</sup>" and insert --mA/cm<sup>2</sup>--.

At page 45, line 20, after "atoms/cm<sup>3</sup>" please delete "," and insert ---.

IN THE CLAIMS:

Kindly amend Claims 5 and 6 in accordance with 37 CFR 1.121(b) as follows:

5. (Amended) A method as defined in Claim 3, wherein in the anodizing

9/a  
4-14-99  
C. Stanley

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